



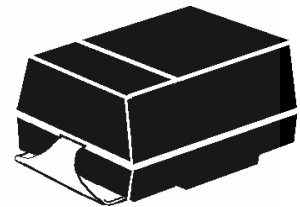
500 WATT LOW CAPACITANCE TRANSIENT VOLTAGE SUPPRESSOR

DESCRIPTION

The HSMBJSAC transient voltage suppressor (TVS) series rated at 500 Watts provides an added rectifier element as shown in Figure 4 to achieve low capacitance in applications for data or signal lines. The low capacitance rating of less than 30 pF may be used for protecting higher frequency applications in inductive switching environments or electrical systems involving secondary lightning effects per IEC61000-4-5 as well as RTCA/DO-160D or ARINC 429 for airborne avionics. If bidirectional protection is needed, two HSMBJSAC devices in anti-parallel configuration are required as shown in Figure 6. With their very fast response time, they also provide ESD and EFT protection per IEC61000-4-2 and IEC61000-4-4 respectively.

IMPORTANT: For the most current data, consult MICROSEMI's website: <http://www.microsemi.com>

APPEARANCE



DO-214AA
See package notes

FEATURES

- Unidirectional low-capacitance TVS series (for bidirectional see Figure 6)
- Suppresses transient up to 500 Watts Peak Pulse Power @ 10/1000 μ s
- Improved performance in low capacitance of 30 pF
- Economical small plastic surface mount with robust axial subassembly package
- Options for screening in accordance with MIL-PRF-19500 for JAN, JANTX, JANTXV, and JANS are also available by adding MQ, MX, MV, or MSP prefixes respectively to part number, e.g. MXSAC5.0, MVSAC18, etc.
- Also available in surface mount with SMAJ prefix for part numbers (ex. SMAJSAC5.0)
- UL94V-0 Flammability Classification

APPLICATIONS / BENEFITS

- Low Capacitance for data-line protection to 70 MHz
- Protection for aircraft fast data rate lines per select level waveforms in RTCA/DO-160D & ARINC 429
- ESD and EFT protection per IEC61000-4-2 and IEC61000-4-4 respectively
- Secondary lightning protection per IEC61000-4-5 with 42 Ohms source impedance:
 - Class 1: HSMBJSAC5.0 to HSMBJSAC50
 - Class 2: HSMBJSAC5.0 to HSMBJSAC45
 - Class 3: HSMBJSAC5.0 to HSMBJSAC22
 - Class 4: HSMBJSAC5.0 to HSMBJSAC10
- Secondary lightning protection per IEC61000-4-5 with 12 Ohms source impedance
 - Class 1: HSMBJSAC5.0 to HSMBJSAC26
 - Class 2: HSMBJSAC5.0 to HSMBJSAC15
 - Class 3: HSMBJSAC5.0 to HSMBJSAC7.0

MAXIMUM RATINGS

- Peak Pulse Power Dissipation at 25°C: 500 Watts @ 10/1000 μ s with repetition rate of 0.01% or less*
- Steady State Power Dissipation* at $T_L = +75^\circ\text{C}$: 2.5 Watts.
- Clamping Speed (0 volts to $V_{(BR)}$ Min.) less than 5 nanoseconds.
- Operating and Storage Temperature: -65°C to $+150^\circ\text{C}$.

MECHANICAL AND PACKAGING

- CASE: Void Free Transfer Molded Thermosetting Plastic (see DO-214AA dimensions and notes)
- FINISH: All External Surfaces Are Corrosion Resistant and Leads Solderable
- POLARITY: Cathode (TVS) Marked with Band
- MARKING: Part number without HSMBJ prefix (ie. SAC5.0)
- WEIGHT: 0.1 Grams (Approx.)

* TVS devices are not typically used for dc power dissipation and are instead operated $\leq V_{WM}$ (rated standoff voltage) except for transients that briefly drive the device into avalanche breakdown (V_{BR} to V_C region) of the TVS element. Also see Figures 5 and 6 for further protection details in rated peak pulse power for unidirectional and bidirectional configurations respectively.



HSMBJSAC5.0 thru HSMBJSAC50

500 WATT LOW CAPACITANCE TRANSIENT VOLTAGE SUPPRESSOR

ELECTRICAL CHARACTERISTICS @ 25°C

MICROSEMI PART NUMBER	REVERSE STAND-OFF VOLTAGE (Note 1) V_{WM} Volts	BREAKDOWN VOLTAGE @ $I_{(BR)} 1.0mA$ $V_{(BR)}$ Volts Min.	MAXIMUM STANDBY CURRENT @ V_{WM} I_D μA	MAXIMUM CLAMPING VOLTAGE $I_P = 5.0A^*$ V_C Volts	MAXIMUM PEAK PULSE CURRENT* RATING I_{PP} Amps	CAPACITANCE @ 0 Volts pF	WORKING INVERSE BLOCKING VOLTAGE V_{WIB} Volts	INVERSE BLOCKING LEAKAGE CURRENT @ V_{WIB} I_{IB} mA	PEAK INVERSE BLOCKING VOLTAGE V_{PIB} Volts
HSMBJSAC5.0	5.0	7.60	300	10.0	44	30	75	1	100
HSMBJSAC6.0	6.0	7.90	300	11.2	41	30	75	1	100
HSMBJSAC7.0	7.0	8.33	300	12.6	38	30	75	1	100
HSMBJSAC8.0	8.0	8.89	100	13.4	36	30	75	1	100
HSMBJSAC8.5	8.5	9.44	50	14.0	34	30	75	1	100
HSMBJSAC10	10	11.10	5.0	16.3	29	30	75	1	100
HSMBJSAC12	12	13.30	5.0	19.0	25	30	75	1	100
HSMBJSAC15	15	16.70	5.0	23.6	20	30	75	1	100
HSMBJSAC18	18	20.00	5.0	28.8	15	30	75	1	100
HSMBJSAC22	22	24.40	5.0	35.4	14	30	75	1	100
HSMBJSAC26	26	28.90	5.0	42.3	11.1	30	75	1	100
HSMBJSAC36	36	40.0	5.0	60.0	8.6	30	75	1	100
HSMBJSAC45	45	50.00	5.0	77.0	6.8	30	150	1	200
HSMBJSAC50	50	55.50	5.0	88.0	5.8	30	150	1	200

*See Figure 3

Clamping Factor: The ratio of the numerical value of V_C to $V_{(BR)}$ is typically 1.4 @ full rated power, 1.20 @ 50% rated power. Also see MicroNote 108.

Note 1: A transient voltage suppressor is normally selected according to voltage (V_{WM}), that should be equal to or greater than the dc or continuous peak operating voltage level.

Note 2: When pulse testing, test in TVS avalanche direction. Do not pulse in "forward" direction. See section for "Schematic Applications" herein.

GRAPHS

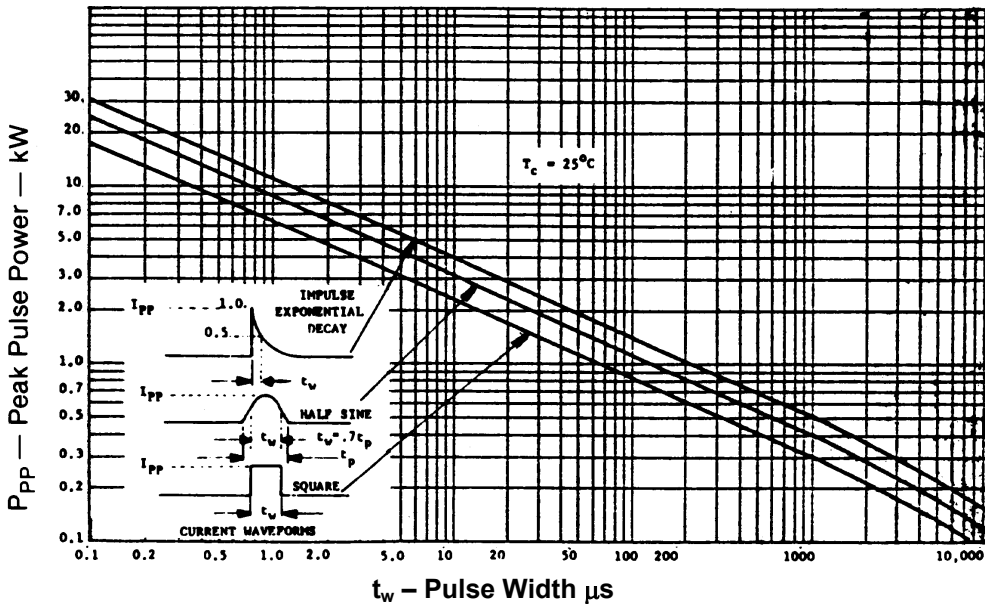
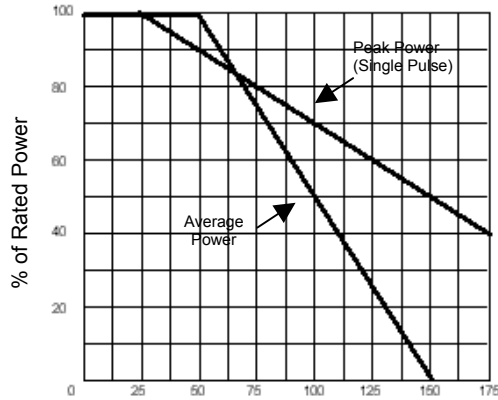


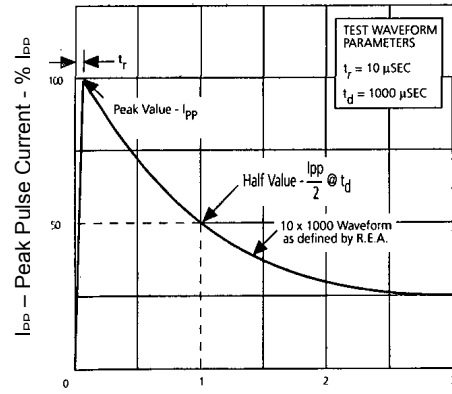
FIGURE 1



T_L – Lead Temperature – °C

FIGURE 2

Lead Length = 3/8"



t – Time – msec

FIGURE 3

SCHEMATIC APPLICATIONS

The TVS low capacitance device configuration is shown in Figure 4. As a further option for unidirectional applications, an additional low capacitance rectifier diode may be used in parallel in the same polarity direction as the TVS as shown in Figure 5. In applications where random high voltage transients occur, this will prevent reverse transients from damaging the internal low capacitance rectifier diode and also provide a low voltage conducting direction. The added rectifier diode should be of similar low capacitance and also have a higher reverse voltage rating than the TVS clamping voltage V_C. Consult factory for recommended rectifier part number. If using two (2) low capacitance TVS devices in anti-parallel for bidirectional applications, this added protective feature for both directions (including the reverse of each rectifier diode) is also provided. The unidirectional and bidirectional configurations in Figure 5 and 6 will both result in twice the capacitance of Figure 4.

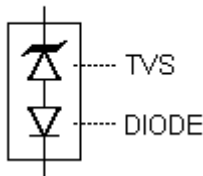


FIGURE 4

TVS with internal Low Capacitance Diode

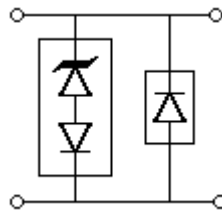


FIGURE 5

Optional Unidirectional configuration (TVS and separate rectifier diode) in parallel)

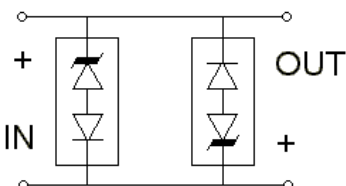
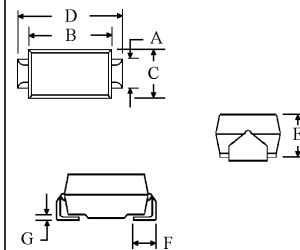


FIGURE 6 Optional Bidirectional configuration (two TVS devices in anti-parallel)

PACKAGE DIMENSIONS



DIM	DIMENSIONS			
	INCHES		MILLIMETERS	
	MIN	MAX	MIN	MAX
A	.073	.087	1.85	2.21
B	.160	.180	4.06	4.57
C	.130	.155	3.30	3.94
D	.205	.220	5.21	5.59
E	.075	.130	1.91	3.30
F	.030	.060	.76	1.52
G	.006	.016	.15	.41

NOTE: Dimension E exceeds the JEDEC outline in height as shown